IN THE SPECIFICATION:

Please amend paragraph [0030] through [0033] as follows:

[0030] After forming the array substrate 23 that includes the lower substrate 22, the gate insulation layer 33, the passivation layer 35, the TFT and etc, the upper substrate 5 having the common electrode 18 is aligned and attached to the array substrate 23 using the sealant 2 (i.e., the seal pattern). As the sealant 2 is mainly used for attaching the upper substrate 5 to the array substrate 23, the sealant 2 is positioned between the common electrode 18 and the passivation layer (organic material) 35, as shown in FIG. ~~5A~~ 5.

[0031] ~~FIG. 5B is an enlarged view of a portion "F" of FIG. 5A according to the background art. As shown in the drawing, the~~ The passivation layer 35 and the gate insulation layer 33, which are respectively formed of the organic material and the inorganic material, have an etching hole [[37]] (not shown in FIG. 5) in a seal pattern area having a width [["W"]]. Since the sealant 2 does not have good adhesive force to the organic material (the passivation layer 35), the sealant 2 often bursts. Because of this problem, the etching hole [[37]] is formed in the array substrate 23.

[0032] In the seal pattern area, the passivation layer 35 is mostly etched out, and thus, the sealant 2 may contact the inorganic material (the gate insulation layer 33). Thus, the sealant 2 does not largely contact the organic material (the passivation layer 35) that has a

lower adhesive force to the sealant 2. Moreover, owing to the etching hole [[37]], the contacting area increases between the sealant 2 and the array substrate 23.

[0033] However, the above-mentioned structure does not provide a required adhesion, and also it does not sufficiently enlarge the seal pattern area that is the contacting area between the seal pattern 2 and the array substrate 23. Accordingly, it is essential to obtain the large seal pattern area and to increase the contacting area in the liquid crystal panel. Moreover, to obtain a large contacting area, enlarging the width ~~"W"~~ of the seal pattern 2 is not good enough because of an aperture ratio. As a result, it reaches the limit to enlarge the width ~~"W"~~.

Please amend paragraph [0050] to read as follows:

[0050] FIG. [[5B]] 5 is an enlarged cross-sectional view taken along line V-V of FIG. 4

Please delete paragraph [0051] in its entirety.

IN THE DRAWINGS:

Applicant respectfully submits herewith a Submission of Replacement Drawings including 8 sheets of drawing containing 21 drawing figures to be substituted for the previously filed drawing sheets in the above-identified application. Applicant has amended originally-filed FIG. 5A to read "FIG. 5," and deleted previously-filed FIG. 5B. Applicant respectfully submits that no new matter is introduced by the replacement drawings.